Key Features



- 0.5 ~ 3.0 GHz
- 1.0 dB Noise Figure
- 20.0 dBm Min Output IP₃
- 15.5 dB Gain
- +/-0.5 dB Gain Flatness
- 10.0 ~ 14.0 dBm P_{1dB}
- 1.35:1 VSWR Fully Matched
- Single Power Supply
- >300 Years MTBF
- RoHS Compliant
- MLS-1 Moisture Sensitivity Level

Product Description

WEA108 integrates WanTcom proprietary low noise amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and unconditional stable performances together. With single +5.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard SMA connectorized WP-10E gold plated housing.

The amplifier is designed to meet the rugged standard of MIL-STD-202.

Applications

- Mobile Infrastructures
- GPS
- CATV/DBS
- WiMAX
- Security System
- Measurement
- Fixed Wireless



Specifications

Summary of the electrical specifications WEA108 at room temperature

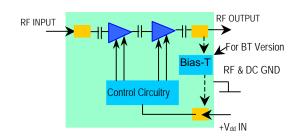
Index	Testing Item	Symbol	Test Constraints		Nom	Max	Unit
1	Gain	S ₂₁	0.5 – 3.0 GHz		15.5	16.5	dB
2	Gain Variation	ΔG	0.5 – 3.0 GHz		+/- 0.5	+/-1.0	dB
3	Input VSWR	SWR ₁	0.5 – 3.0 GHz			1.6:1	Ratio
4	Output VSWR	SWR ₂	0.5 – 3.0 GHz			1.5:1	Ratio
5	Reverse Isolation	S ₁₂	0.5 – 3.0 GHz	16			dB
6	Noise figure	NF	0.5 – 3.0 GHz		1.0	1.2	dB
7	Output Power 1dB compression Point	P _{1dB}	0.5 – 3.0 GHz	9		15	dBm
8	Output-Third-Order Interception point	IP ₃	Two-Tone, P _{out} +0 dBm each, 1 MHz separation	20			dBm
9	Current Consumption	I _{dd}	V _{dd} = +5.0 V		20		mA
10	Power Supply Voltage	V_{dd}		+4.7	+5	+5.3	V
11	Thermal Resistance	R _{th,c}	Junction to case			215	°C/W
12	Operating Temperature	To		-40		+85	°C
13	Maximum Average RF Input Power	P _{IN, MAX}	DC - 6.0 GHz			10	dBm

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	-0.5 ~ +7.0
Drain Current	mA	40
Total Power Dissipation	mW	280
RF Input Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-65 ~ 150
Operating Temperature	°C	-55 ~ +100
Thermal Resistance	°C/W	215

Operation of this device above any one of these parameters may cause permanent damage.

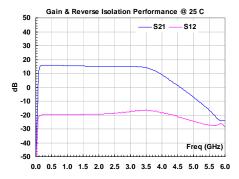
Functional Block Diagram

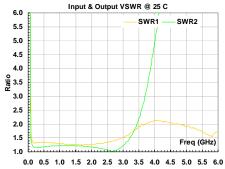


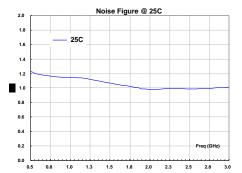
Ordering Information

Model Number	Feature		
WEA108	Without Bias-T at Output		
WEA108BT	With Bias-T at Output		

Typical Data

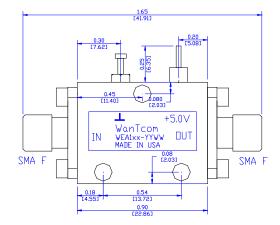


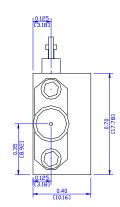




Outline, WP-10E Housing

UNITS: INCH [mm]
BODY: Brass
Finish: Gold Plating
RF Connector: SMA F Gold
V_{dd} PWR: Feed through





Application Notes:

SMA Torque Wrench Selection

Always use a torque wrench with $5 \sim 6$ inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The $24 \sim 26$ American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.
